

### Product Features

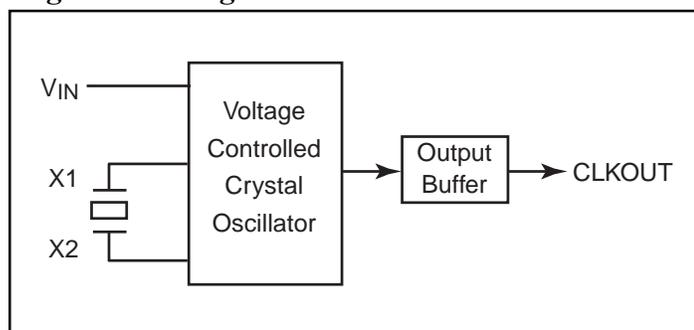
- 3.3V operating voltage
- Uses an inexpensive external crystal
- On-chip VCXO with pull range of 240ppm
- VCXO tuning voltage from 0 to 3.3V
- 10mA output drive at CMOS levels
- Available in SOIC package

### Product Description

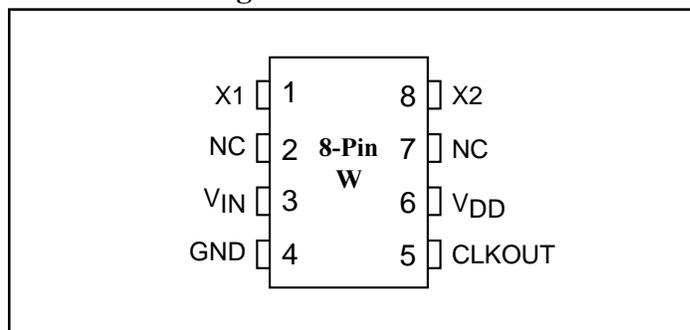
The PI6CX100-35 is a low-cost, high-performance 3.3V VCXO, designed to replace expensive VCXO modules. The on-chip Voltage Controlled Crystal Oscillator accepts a 0 to 3.3V input voltage to cause clocks to vary by  $\pm 120$ ppm. This device uses an inexpensive external pullable crystal at 35 MHz to produce the same output frequency.

The PI6CX100-35 is designed for xDSL applications.

### Logic Block Diagram



### Product Pin Configuration



### Pin Description

Pin Name	Pin Number	Type	Description
X1, X2	1, 8	I	Crystal Connection
NC	2, 7		No Connect
V <sub>IN</sub>	3	I	Voltage Input to VCXO
GND	4	PWR	Ground
CLKOUT	5	O	Clock Output
V <sub>DD</sub>	6	PWR	Power Supply <sup>(1)</sup>

#### Note:

1. 0.1 $\mu$ F or 0.01 $\mu$ F bypass capacitor is required.

### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature .....	-55°C to 125°C
Ambient Temperature .....	-40°C to 85°C
Supply Voltage $V_{DD}$ .....	-0.5V to 7V
Inputs/Outputs Voltage .....	-0.5V to $V_{DD}+0.5V$
Output Current .....	10mA
Soldering Lead Temperature (10s) .....	260°C
Junction Temperature .....	-50°C to 150°C

**Note:**

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### DC Electrical Characteristics

(Unless otherwise specified,  $V_{DD} = 3.3V$ ,  $f_0 = 35.328\text{ MHz}$ ,  $V_{IN} = 1.65V$ , Load = 15pF,  $T_A = 25^\circ\text{C}$ )

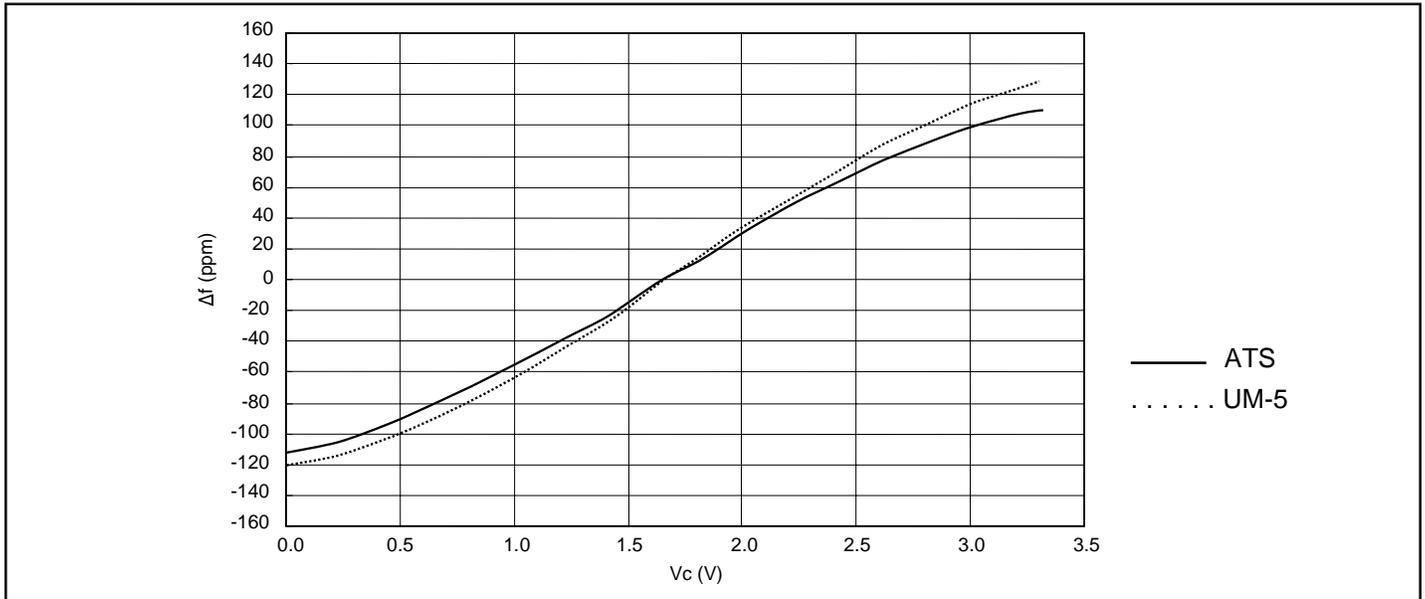
Symbol	Description	Test Condition	Min.	Typ.	Max.	Units
$V_{DD}$	Operating Voltage		3.135	3.3	3.465	V
$V_{OH}$	Output High Voltage	$I_{OH} = -12\text{mA}$	2.8			
$V_{OL}$	Output Low Voltage	$I_{OL} = 12\text{mA}$			0.5	
$I_{OH}$	Output High Current	$V_{OH} = V_{DD} - 0.5V$		-11	-4	mA
$I_{OL}$	Output Low Current	$V_{OL} = 0.5V$	4	12		
$I_{DD}$	Supply Current	$C_L = 15\text{pF}$		6		
$I_{OZ}$	Output Off-leakage				10	$\mu\text{A}$
$R_S$	Negative Resistance	$V_{IN} = 0V$		-80		$\Omega$
$f_0$	Input Frequency			35		MHz
$C_L$	Output Load Capacitance			15	30	pF

### AC Electrical Characteristics

(Unless otherwise specified,  $f_0 = 35.328\text{ MHz}$ , Load = 15pF,  $T_A = 25^\circ\text{C}$ )

Symbol	Description	Test Condition	Min.	Typ.	Max.	Units
$T_r / T_f$	Rise / Fall Time	$0.1V_{DD} - 0.9V_{DD}$		1.5	6	Ns
$T_d$	Duty Cycle	$0.5V_{DD}$	45		55	%
$T_j$	Cycle-to-Cycle Jitter	$C_L = 15\text{pF}$		50		ps
$\Delta f$	Pull Range	$V_{IN} = 0 - V_{DD}$		$\pm 120$		ppm
$L_{in}$	Linearity	$V_{IN} = 0.1V_{DD} - 0.9V_{DD}$		$\pm 10$		%
	Oscillator start time	$V_{DD} = 0.9V_{DD}$ trigger		1.5	10	ms

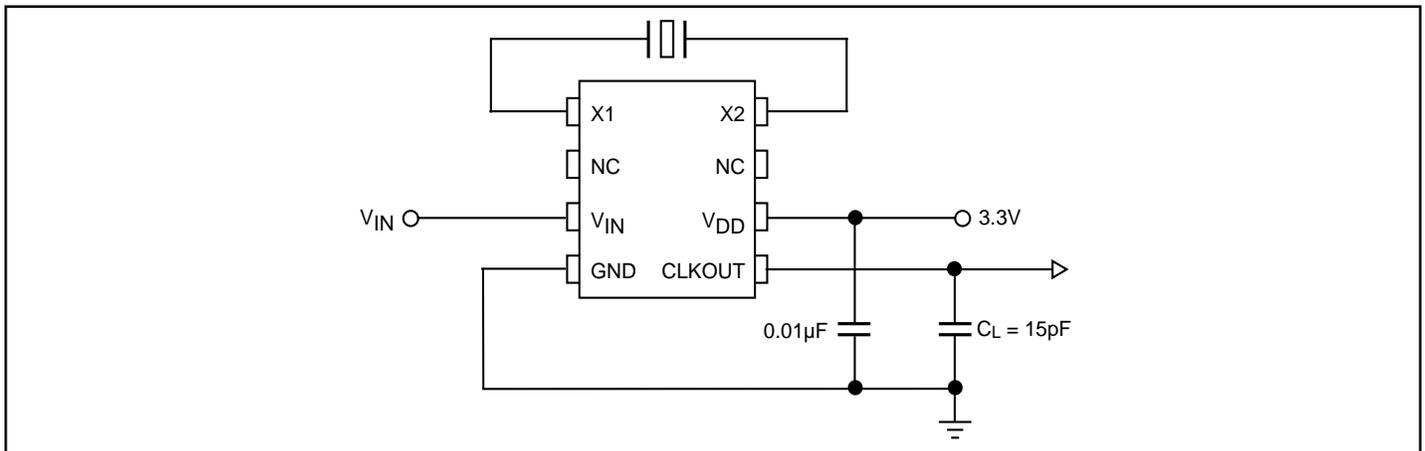
### Pullability Characteristics



### Recommended Crystal Specifications

Description	Crystal
Mode of Oscillation	Fundamental
Frequency Range	35.328 MHz
Frequency Tolerance	$\pm 20$ ppm
Temperature plus Aging Stability	$\pm 50$ ppm
Operating Temperature	$-20^\circ\text{C}$ to $+70^\circ\text{C}$
C0 / C1	240 (max.)
Load Capacitance ( $C_L$ )	17pF
Equivalent Series Resistance (ESR)	35 ohms (max.)

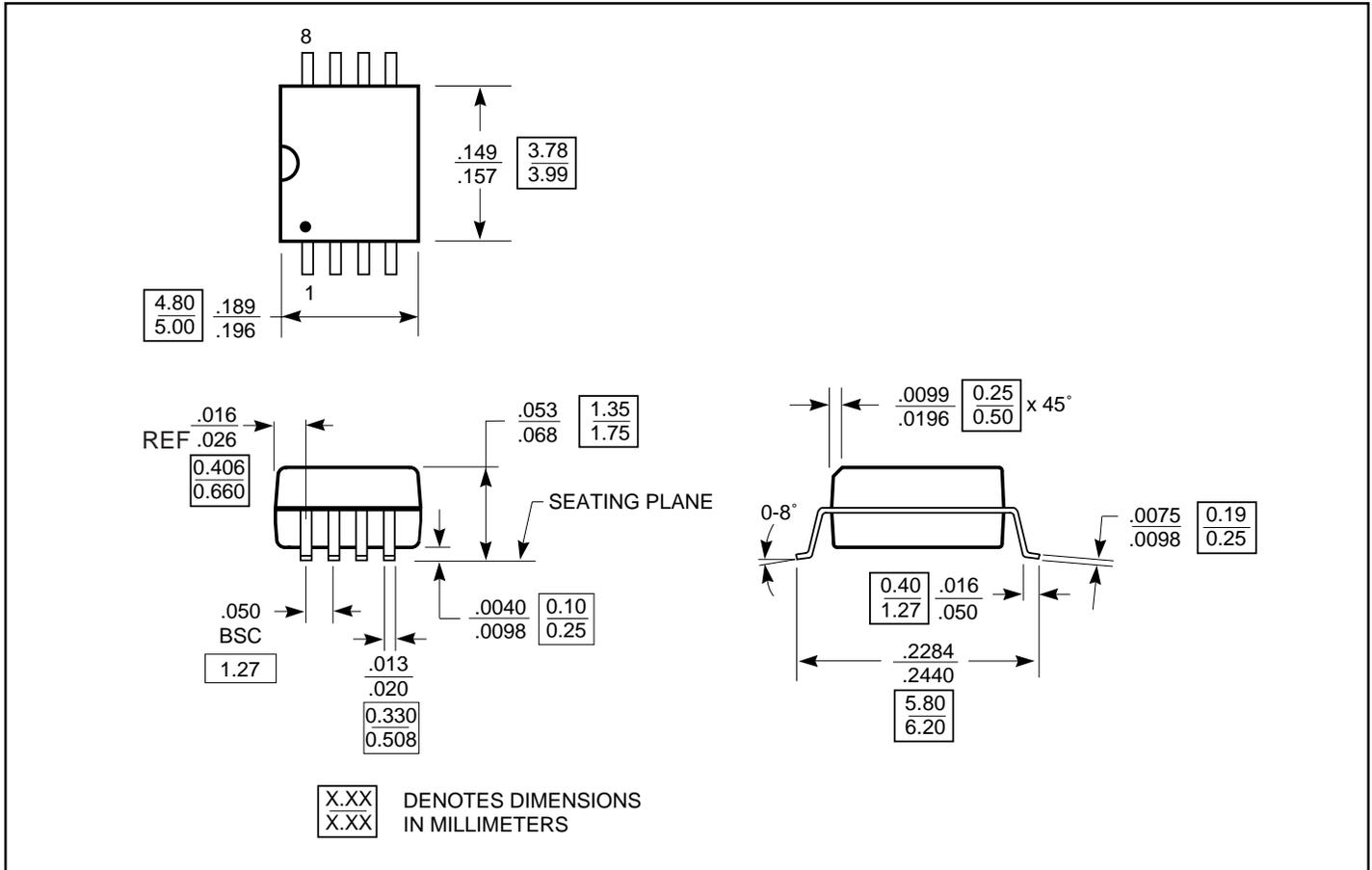
### Measurement Circuit



**Note:**

1. 0.1  $\mu\text{F}$  or 0.01  $\mu\text{F}$  bypass capacitor is required.
2. Crystal frequency is 35.328 MHz.

**Plastic 8-pin SOIC Package**



**Ordering Information**

Ordering Code	Package Name	Package Type	Operating Range
PI6CX100-35W	W8	8-pin 150-mil SOIC	Industrial